

FGL40N120AN

1200V NPT IGBT

Features

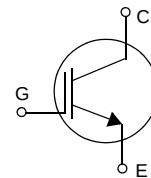
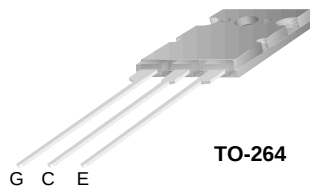
- High speed switching
- Low saturation voltage : $V_{CE(sat)} = 2.6 \text{ V @ } I_C = 40 \text{ A}$
- High input impedance

Applications

Induction Heating, UPS, AC & DC motor controls and general purpose inverters.

Description

Employing NPT technology, Fairchild's AN series of IGBTs provides low conduction and switching losses. The AN series offers an solution for application such as induction heating (IH), motor control, general purpose inverters and uninterruptible power supplies (UPS).



Absolute Maximum Ratings

Symbol	Parameter	FGL40N120AN	Units
V_{CES}	Collector-Emitter Voltage	1200	V
V_{GES}	Gate-Emitter Voltage	± 25	V
I_C	Collector Current @ $T_C = 25^\circ\text{C}$	64	A
	Collector Current @ $T_C = 100^\circ\text{C}$	40	A
$I_{CM(1)}$	Pulsed Collector Current	160	A
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	500	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	200	W
SCWT	Short Circuit Withstand Time, $V_{CE} = 600\text{V}, V_{GE} = 15\text{V}, T_C = 125^\circ\text{C}$	10	μs
T_J	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_L	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 seconds	300	$^\circ\text{C}$

Notes:

(1) Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction-to-Case	--	0.25	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	--	25	$^\circ\text{C/W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGL40N120AN	FGL40N120AN	TO-264	-	-	25

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} = 0V, I _C = 1mA	1200	--	--	V
BV _{CES} /ΔT _J	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0V, I _C = 1mA	--	0.6	--	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0V	--	--	1	mA
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0V	--	--	±250	nA
On Characteristics						
V _{GE(th)}	G-E Threshold Voltage	I _C = 250μA, V _{CE} = V _{GE}	3.5	5.5	7.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 40A, V _{GE} = 15V	--	2.6	3.2	V
		I _C = 40A, V _{GE} = 15V, T _C = 125°C	--	2.9	--	V
		I _C = 64A, V _{GE} = 15V	--	3.15	--	V
Dynamic Characteristics						
C _{ies}	Input Capacitance	V _{CE} = 30V, V _{GE} = 0V f = 1MHz	--	3200	--	pF
C _{oes}	Output Capacitance		--	370	--	pF
C _{res}	Reverse Transfer Capacitance		--	125	--	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{CC} = 600V, I _C = 40A, R _G = 5Ω, V _{GE} = 15V, Inductive Load, T _C = 25°C	--	15	--	ns
t _r	Rise Time		--	20	--	ns
t _{d(off)}	Turn-Off Delay Time		--	110	--	ns
t _f	Fall Time		--	40	80	ns
E _{on}	Turn-On Switching Loss		--	2.3	3.45	mJ
E _{off}	Turn-Off Switching Loss		--	1.1	1.65	mJ
E _{ts}	Total Switching Loss	V _{CC} = 600V, I _C = 40A, R _G = 5Ω, V _{GE} = 15V, Inductive Load, T _C = 125°C	--	3.4	5.1	mJ
t _{d(on)}	Turn-On Delay Time		--	20	--	ns
t _r	Rise Time		--	25	--	ns
t _{d(off)}	Turn-Off Delay Time		--	120	--	ns
t _f	Fall Time		--	45	--	ns
E _{on}	Turn-On Switching Loss		--	2.5	--	mJ
E _{off}	Turn-Off Switching Loss	V _{CE} = 600V, I _C = 40A, V _{GE} = 15V	--	1.8	--	mJ
E _{ts}	Total Switching Loss		--	4.3	--	mJ
Q _g	Total Gate charge		--	220	330	nC
Q _{ge}	Gate-Emitter Charge	V _{CE} = 600V, I _C = 40A, V _{GE} = 15V	--	25	38	nC
Q _{gc}	Gate-Collector Charge		--	130	195	nC

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

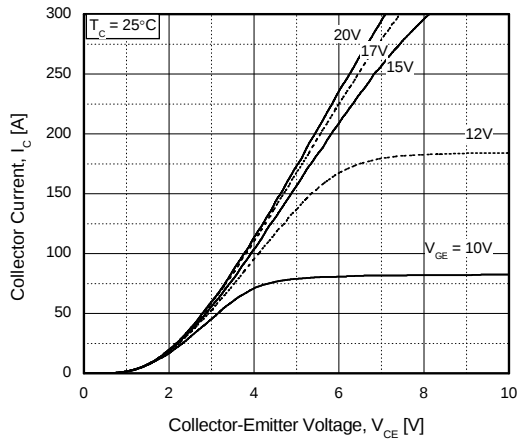


Figure 2. Typical Saturation Voltage Characteristics

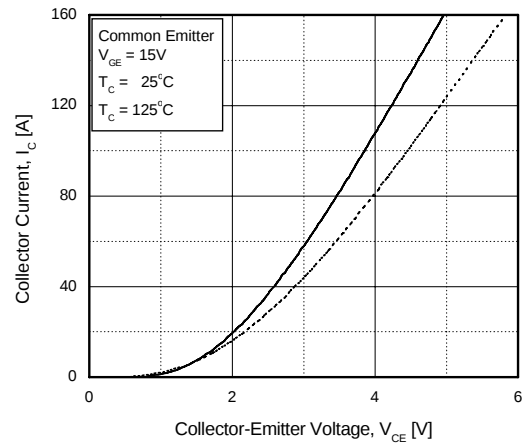


Figure 3. Saturation Voltage vs. Case Temperature at Variant Current Level

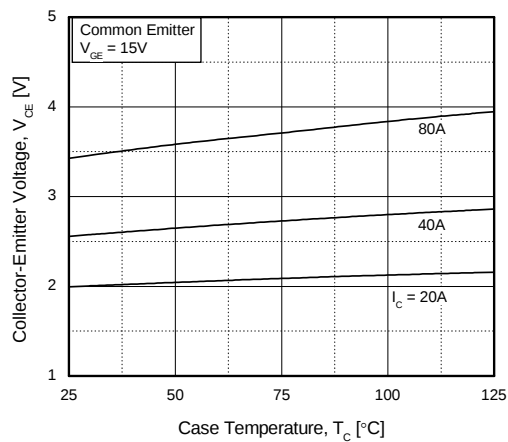


Figure 4. Load Current vs. Frequency

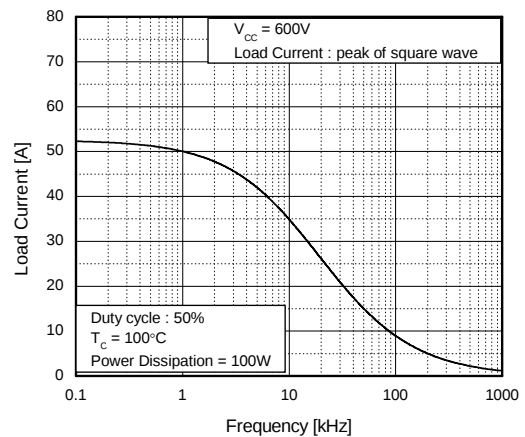


Figure 5. Saturation Voltage vs. V_{GE}

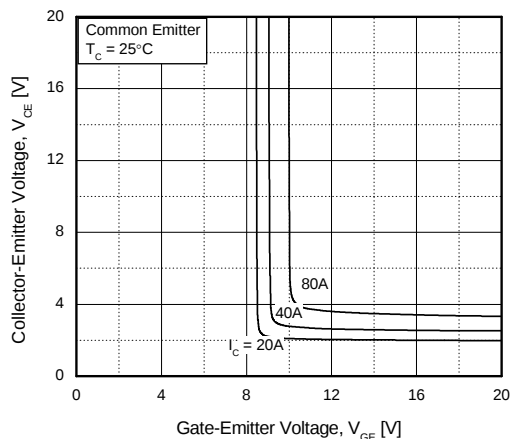
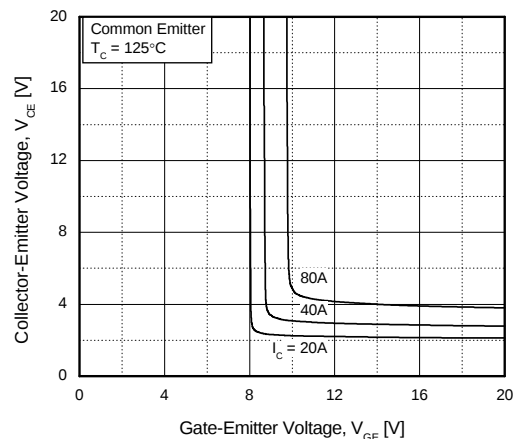


Figure 6. Saturation Voltage vs. V_{GE}



Typical Performance Characteristics (Continued)

Figure 7. Capacitance Characteristics

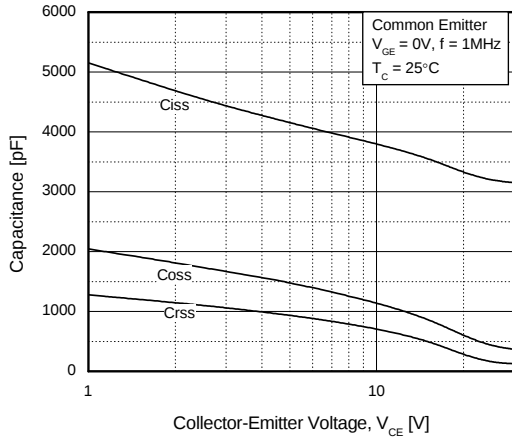


Figure 8. Turn-On Characteristics vs. Gate Resistance

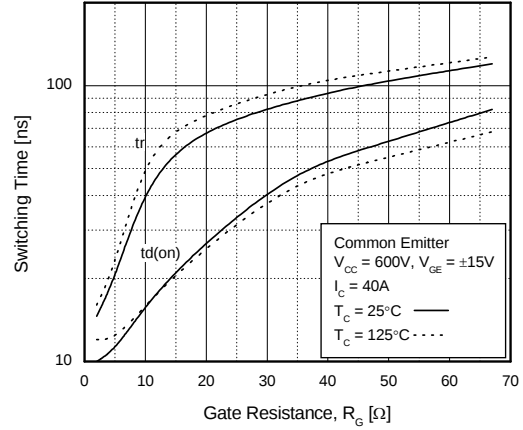


Figure 9. Turn-Off Characteristics vs. Gate Resistance

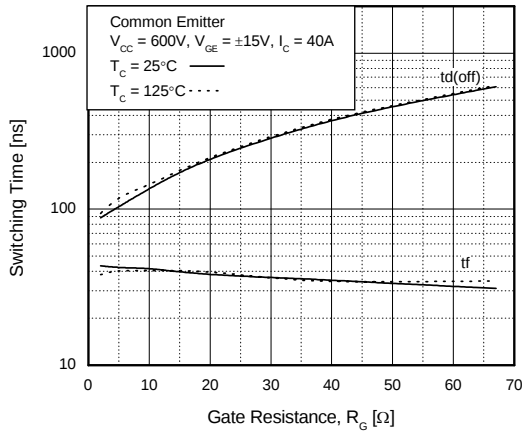


Figure 10. Switching Loss vs. Gate Resistance

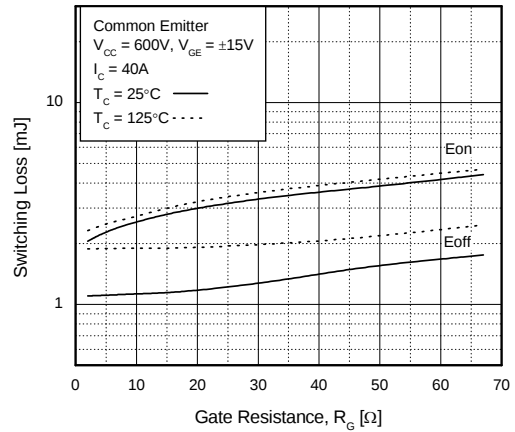


Figure 11. Turn-On Characteristics vs. Collector Current

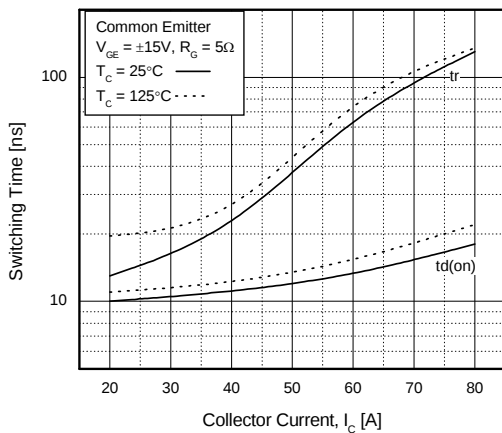
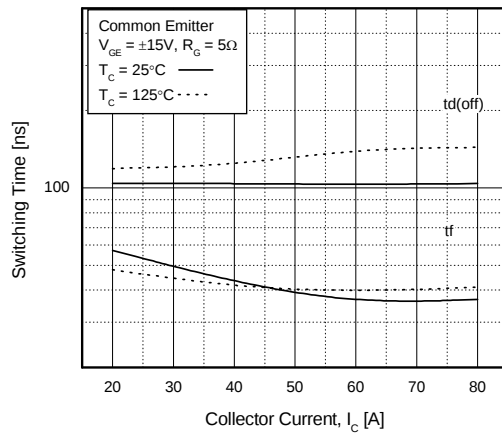


Figure 12. Turn-Off Characteristics vs. Collector Current



Typical Performance Characteristics (Continued)

Figure 13. Switching Loss vs. Collector Current

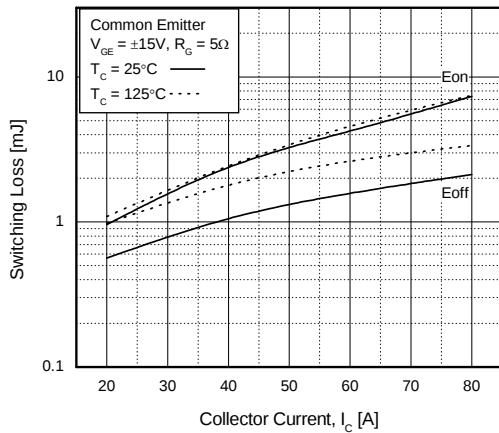


Figure 14. Gate Charge Characteristics

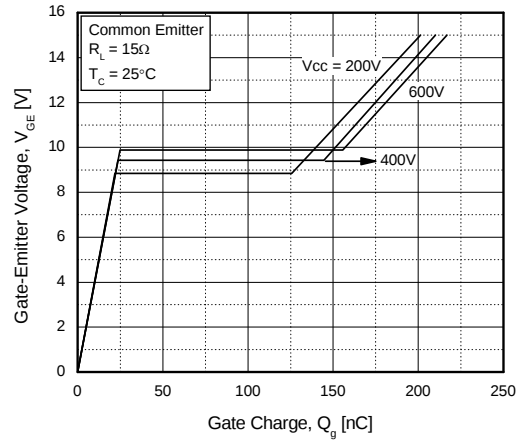


Figure 15. SOA Characteristics

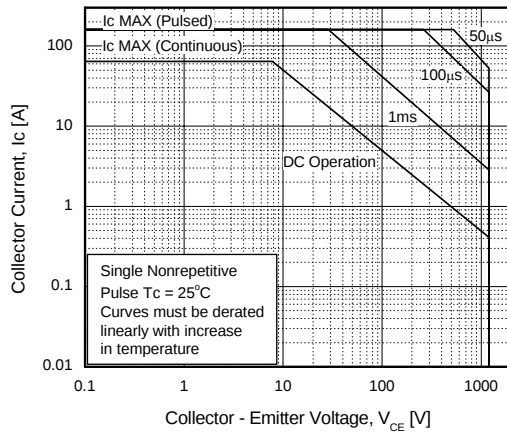


Figure 16. Turn-Off SOA

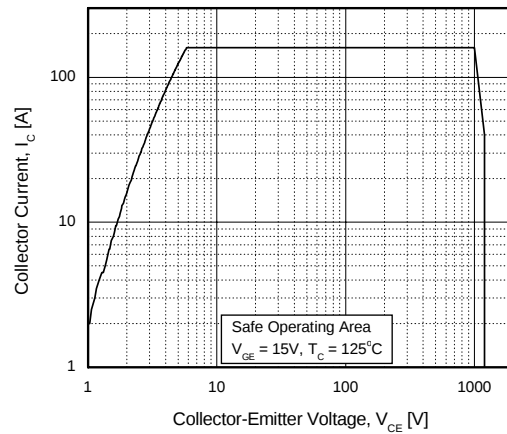
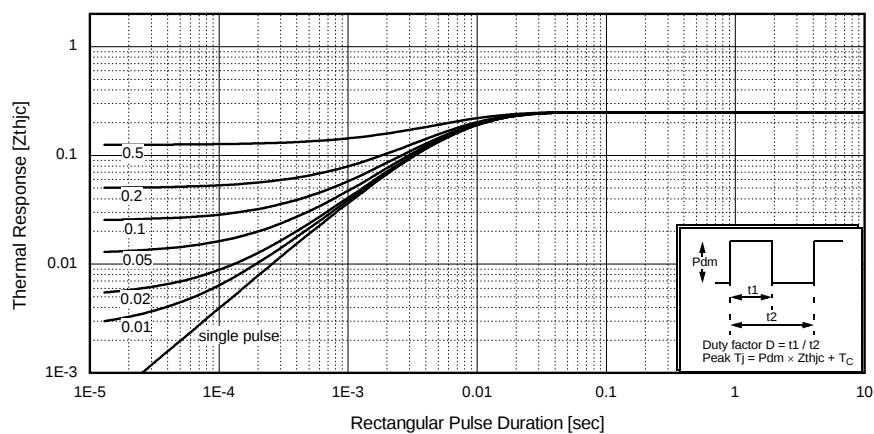
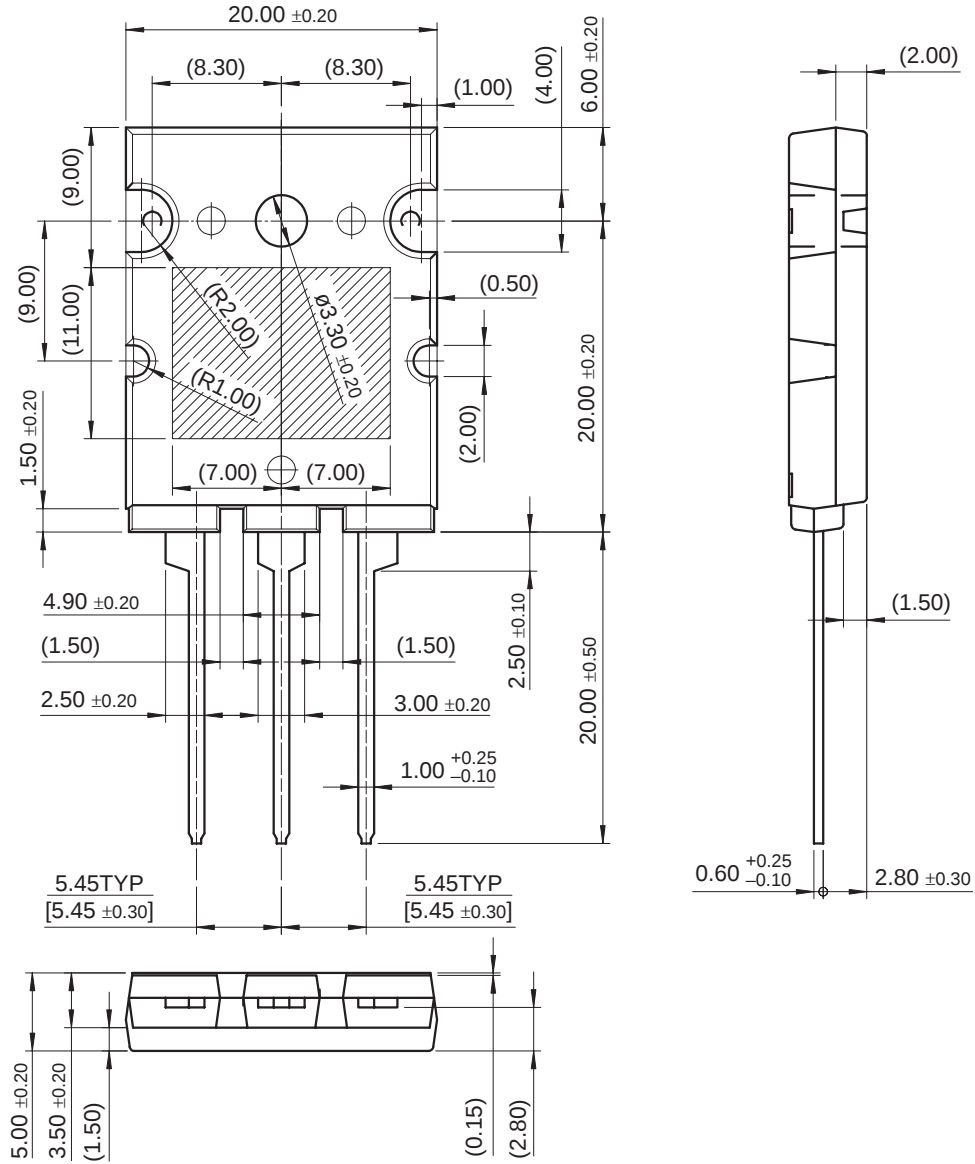


Figure 17. Transient Thermal Impedance of IGBT



Mechanical Dimensions

TO-264



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks and service marks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACE [®]	Green FPS [™] e-Series [™]	POWEREDGE [®]	SuperSOT [™] -8
Build it Now [™]	GTO [™]	Power-SPM [™]	SyncFET [™]
CorePLUS [™]	<i>i-Lo</i> [™]	PowerTrench [®]	The Power Franchise [®]
CROSSVOLT [™]	IntelliMAX [™]	Programmable Active Droop [™]	 [™]
CTL [™]	ISOPLANAR [™]	QFET [®]	TinyBoost [™]
Current Transfer Logic [™]	MegaBuck [™]	QS [™]	TinyBuck [™]
EcoSPARK [®]	MICROCOUPLER [™]	QT Optoelectronics [™]	TinyLogic [®]
FACT Quiet Series [™]	MicroFET [™]	Quiet Series [™]	TINYOPTO [™]
FACT [®]	MicroPak [™]	RapidConfigure [™]	TinyPower [™]
FAST [®]	Motion-SPM [™]	SMART START [™]	TinyPWM [™]
FastvCore [™]	OPTOLOGIC [®]	SPM [®]	TinyWire [™]
FPS [™]	OPTOPLANAR [®]	STEALTH [™]	μSerDes [™]
FRFET [®]	PDP-SPM [™]	SuperFET [™]	UHC [®]
Global Power Resource SM	Power220 [®]	SuperSOT [™] -3	UniFET [™]
Green FPS [™]	Power247 [®]	SuperSOT [™] -6	VCX [™]

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild Semiconductor. The datasheet is printed for reference information only.

Rev. I29